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Authors
Li, Zhi-Pan
Petracic, Oleg
Morales, Rafael
et al.

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Asymmetric Reversal in Inhomogeneous Magnetic Heterostructures

Zhi-Pan Li,1,∗ Oleg Petracci,1,2 Rafael Morales,1,3 Justin Olamit,4 Xavier Batlle,1,5 Kai Liu,4 and Ivan K. Schuller1

1Physics Department, University of California - San Diego, La Jolla, California, 92093-0319, USA
2Angewandte Physik, Universität Duisburg-Essen, 47048 Duisburg, Germany
3Departamento de Física, Universidad de Oviedo, Oviedo 33007, Spain
4Physics Department, University of California, Davis, California 95616, USA
5Departament de Física Fonamental, Universitat de Barcelona, 08028 Barcelona, Spain

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Asymmetric magnetization reversal is an unusual phenomenon in antiferromagnet/ferromagnet (AF/FM) exchange biased bilayers. We investigated this phenomenon in a simple model system experimentally and by simulation assuming inhomogeneously distributed interfacial AF moments. The results suggest that the observed asymmetry originates from the intrinsic broken symmetry of the system, which results in local incomplete domain walls parallel to the interface in reversal to negative saturation of the FM. The magneto-optical Kerr effect unambiguously confirms such an asymmetric reversal in a depth-dependent FM domain wall in accord with the magnetometry and simulations.

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Exchange coupling between a ferromagnet (FM) and an antiferromagnet (AF) has been intensely studied due to the fundamental interest in inhomogeneous magnetic systems and its central role as a magnetic reference in various devices. In most magnetic systems, time reversal symmetry is present and manifested by a symmetric magnetization curve relative to the origin. This symmetry also requires that the magnetization reversal from positive to negative saturation be identical to the reverse process. However, in a FM/AF system, exchange bias (EB) develops below the AF Néel temperature $T_N$ producing a shift ($H_{EB}$) of the hysteresis loop along the magnetic field axis [1]. Therefore, with the shift breaking the time reversal symmetry, magnetization reversal symmetry is no longer required. In fact, asymmetric reversal was observed by polarized neutron reflectometry [2], photoemission electron microscopy [3], magneto-transport [4], magneto-optical indicator film [5], and magneto-optical Kerr effect [6]. In some systems the reversal along the decreasing branch is dominated by transverse magnetic moments, a phenomenon interpreted as due to coherent magnetic rotation. The absence of transverse moments in the increasing branch reversal was interpreted as domain wall propagation [2,3]. Different, even opposite, scenarios were also found [6–8]. Despite the well established experimental evidence and proposed theoretical models [9–11], the origin of this asymmetry remains a controversial and highly debated issue [12]. This situation is further complicated by the lack of knowledge of the interface, crystal imperfections, complex FM and AF anisotropy energies, and training effect. While these factors are important for each individual system, the fundamental connection of the reversal asymmetry to the broken symmetry intrinsic in the inhomogeneous system is overlooked.

In this Letter, we investigate a simple model system using a variety of experimental techniques combined with numerical simulations. We establish a critical link between this unusual reversal asymmetry with the time reversal asymmetry in these systems. Namely, in reversal toward the two FM saturated states, the intrinsic asymmetry gives rise to different competing mechanisms, thus different reversal processes.

FeF$_2$/(Ni,Py) bilayers were prepared for this study. FeF$_2$ is an AF with a Néel temperature $T_N$ = 78 K, and a large uniaxial anisotropy $K_u$ = $1.35 \times 10^4$ kJ/m$^3$ along the [001] direction, hence can be considered as a model Ising system [13,14], with the AF spins frozen along [001] at low temperatures [15]. The Ni or Py (Ni$_{81}$Fe$_{19}$) is polycrystalline with a negligibly small crystalline anisotropy, except for a small growth-induced uniaxial anisotropy along FeF$_2$ [001] [16]. This system is thus in close approximation with simple theoretical assumptions.

The bilayer was grown by $e$-beam evaporation on a single crystal MgF$_2$(110) substrate, where FeF$_2$(110) grows epitaxially untwinned [16,17]. Vector vibrating sample magnetometry (VSM) of FeF$_2$(50 nm)/Ni(21 nm)/Al(7.6 nm) gives simultaneously the in-plane longitudinal (parallel to the magnetic field) and transverse (perpendicular to the magnetic field) magnetic moments [18,19]. The magnetic field is applied along the FeF$_2$ easy axis [001] with a small misalignment that defines the sign of the transverse component during reversal [12,18]. Square hysteresis loops are found above $T_N$ [001] [16]. Cooling the sample in a field $\mu_0H_{FC} = 0.2$ T from $T = 150$ K to 15 K yields an EB field $\mu_0H_{EB} = -0.1$ T [Fig. 1] and virtually no coercivity. Both longitudinal and transverse hysteresis loops exhibit a clear asymmetry. Starting from positive saturation, the reversal occurs with a sharp corner in the longitudinal component and an abrupt increase in transverse component to over 75% of the saturation magnetization. Then the FM gradually approaches negative saturation, evidenced by the long tail in both components.
obtained from measurements along the hard axis above $T_N$. The dipolar interaction is approximated by a shape anisotropy along the $\hat{z}$ axis (out-of-plane) with $K_d = -(\mu_0/2)M_s^2 = -150 \text{ kJ/m}^3$, which keeps the moments in the sample plane and avoids boundary effects.

The AF is modeled by a monolayer of spatially inhomogeneous frozen moments, $\vec{\sigma}_i$, exchange coupled to the bottom layer of the FM with an adjustable interfacial coupling from $J_{\text{FM/AF}} \sim J_{\text{AF}} = -0.45 \text{ meV up to } 2J_{\text{AF}}$ [13]. We introduced AF grains of average size $25 \times 25 \text{ nm}^2$ to simulate the inhomogeneous interfacial coupling [17]. $\vec{\sigma}_i = -\alpha_j S_j^{\text{AF}} p_j$ with $S_j^{\text{AF}} = 2$ consists of two random quantities: $\alpha_i$ the intergrain variation, and $p_j$ the intragrain variation. $\alpha_i$ varies as $1 \pm 0.35$ between grains, while $p_j$ varies as $(7 \pm 2)\%$ between cells. This 7% assumption is based on recent experiments which found net frozen AF interfacial moments with about 4% [22] or 7% [23] coverage that contribute to EB. Crucial parameters for the simulation include the product of the uncompensated moment coverage and interfacial coupling, and intergrain fluctuation. The former defines the effective coupling strength. The latter describes the interfacial inhomogeneity modulated over a length scale of the grain size (25 nm), comparable with the FM domain wall width 82 nm. This spatial modulation of $\sigma_i$ leads to an inhomogeneous pinning on the FM, and is essential to explain reversal process revealed in the experiment. However, the intensity of the modulation is not essential: 20% to 50% standard deviation in $\alpha_i$ gives similar results. The resultant spatial variation of $\sigma_i$ is shown in the inset of Fig. 1.

The simulation (Fig. 1) is a good match to both the longitudinal and transverse hysteresis loops exhibiting the same asymmetry as the experiment [24]. The bottom and side view of the FM spin configuration during the hysteresis (Fig. 2) shows domains evolving both laterally and in the depth. In positive saturation, the FM is uniformly magnetized throughout the thickness because both the applied magnetic field and interfacial coupling favor this
orientation. As the magnetic field decreases, the reversal is initiated from the top of the FM far away from the interface while the bottom pinned by the AF remains in the positive direction. An incomplete (non-180°) FM domain wall (IDW) is thus formed parallel to the interface. As the field decreases further, these FM IDWs slowly shrink laterally and squeeze close to the interface. Even at $\mu_0 H = -0.8$ T, the FM is not saturated at some interface regions. This lateral domain formation is the result of the spatially varying $\sigma_i$. The regions in the FM most resistant to reversal are where the strongest local interfacial pinning is found. As the field increases, these regions become nucleation sites for the development of local IDWs both laterally and in the depth. Therefore, these local IDWs result from the competition between inhomogeneously distributed interfacial pinning and the magnetic field. Because of the unidirectional nature of the AF pinning field, it only competes with the Zeeman energy in approaching negative saturation, while they both stabilize the FM when positively saturated. This simulation demonstrates that the local development of IDWs constitutes the dominant asymmetric reversal mode. Although similar exchange spring is claimed in hard/soft magnetic structures [25,26], it does not lead to asymmetric reversal [27]. In addition, this incomplete domain wall is unusual in EB because the interfacial coupling energy is much weaker than that in a conventional exchange spring; thus it was never convincingly observed and was overlooked in most EB studies.

When a finite anisotropy of pinned AF moments is included in the simulation, the IDW is pushed into the AF forming a hybrid domain wall across the interface, but the main features of the reversal process remain unchanged. Since the anisotropy of the FM is usually much smaller than that of the AF, the FM side of domain wall dominates the reversal.

The result implies several important features of the local IDW reversal process. First, the FM domain wall depth dependence is crucial for the asymmetric reversal process. An important signature of this behavior is the asymmetric development of transverse magnetic moments. This behavior tends to be smeared out by AF twinning or polycrystallinity, and/or more complicated FM or AF anisotropy energy terms. It is worth noting that this asymmetry of approaching two saturated states may seem different from the asymmetry of two field sweep branches observed before in other systems, where a sharp corner is found in the decreasing branch and a rounded one for the increasing one [4,6]. However, they are essentially the same except for the small FM uniaxial anisotropy, thus negligible coercivity in our system. If the FM uniaxial anisotropy is increased to $K_u = 50$ kJ/m$^3$ and a 0.5° fanning of the AF pinning moment in the sample plane is included, the simulated hysteresis loop displays the same asymmetry as observed before together with an irreversible transverse loop (Fig. 3) [4,6]. Second, the local nature of the IDW due to the interfacial inhomogeneity is crucial in the model. It leads to asymmetric lateral domains due to unsynchronized winding of DW in the depth, and may clarify the present confusion and debate based on lateral multidomain observations. It also explains the long tail of the hysteresis loops, which would otherwise disappear if $\sigma_i$ is not included as in Kiwi’s model (Fig. 3 inset) [28]. Since a square hysteresis loop is observed above $T_N$, this low temperature behavior must arise from the interfacial inhomogeneity.

So far we have demonstrated that the local IDWs nucleated in approaching the negative saturation cause the asymmetric reversal. This result is unambiguously confirmed by magneto-optical Kerr-effect (MOKE) experiments probing the FM-air and FM-AF interfaces independently. In this experiment, a sample with MgF$_2$/(110)/FeF$_2$(50 nm)/Py(70 nm)/Al(4 nm) is cooled below $T_N$ in $\mu_0 H_{FC} = 0.02$ T, and MOKE is performed on both the top and bottom surfaces of the sample with HeNe laser ($\lambda = 632.8$ nm) at 45° incidence [Fig. 4(c)]. Probing the depth dependence of the FM domain structure is possible because the 28 nm penetration depth of the light [29] is less than half of the Py thickness, and both MgF$_2$ and FeF$_2$ are transparent. A clear difference is seen between the two MOKE measurements (Fig. 4). Probing the FM-AF interface shows a much more rounded and longer tail compared with the one from FM-air interface, confirming the existence of domain structures in the depth. The sample was also measured using SQUID magnetometry to which the entire sample contributes equally. The resultant hysteresis loop lies between the two MOKE loops.

We also performed micromagnetic simulations under identical assumptions using the same parameters as above to generate the random frozen AF moments [30]. The exponential decay of MOKE in the FM is simulated by giving each FM discretization layer in the depth an appropriate weight according to the Py 28 nm penetration depth. The resultant hysteresis loops simultaneously with a slight adjustment of the interfacial coupling [31]. At $\mu_0 H = -0.06$ T, a large difference between the two MOKE measurements is observed. The simulated spin configuration at this field shows that the

![FIG. 3 (color online). Simulation of the longitudinal (open symbols) and transverse (filled symbols) hysteresis loop considering 50 kJ/m$^3$ in-plane uniaxial anisotropy and 0.5° fanning of AF uncompensated moment orientation. Inset: Simulated transverse hysteresis loops with uniform (open symbols (red online)) and inhomogeneous (black line) interfacial coupling.](217205-3)

*Email address: zhipan@physics.ucsd.edu

[15] Spin flip is not observed in the samples discussed here.
[24] The interfacial coupling that fits best to the experiment is $J_{FM/AF} = -0.88$ eV, comparable with the exchange coupling in FeF$_2$ $-0.45$ eV from Ref. [13]. This number is not meaningful in its absolute value because it depends on the assumed 7% frozen AF uncompensated moments.
[30] Micromagnetic parameters $M_s = 800$ kA/m and $A = 13$ pJ/m of Py used are from Ref. [21].
[31] The interfacial coupling is found to be $-0.75$ eV.